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FAX COVER SHEET

Page 1 of 5

DATE: 12/20/99

FROM: David Denker COMPANY: Texas Instruments Incorporated PHONE NUMBER: (972) 917-4888 FAX NUMBER: (972) 917-4418	TO: Examiner: B. Su U.S. Patent & Trademark Office Group: 2814 PHONE NUMBER: 703- 305-1481 FAX NUMBER: 703- 308-7722

Re:	Appl. #:	09/116,138
	Atty Docket:	TI-24953
 Rule 111 Reply EOT, 1 month		

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of: Anthony *et al.*

Docket: TI-24953

Serial No.: 09/116,138

Examiner: B. Su

Filed: 07/15/98

Art Unit: 2814

For: High Permittivity Silicate Gate Dielectric

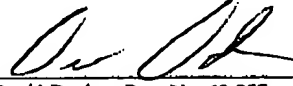
REPLY PURSUANT TO 37 C.F.R. § 1.111

November 18, 1999

Ass't Commissioner for Patents
Washington, DC 20231

Examiner:

FACSIMILE CERTIFICATE
I hereby certify that this correspondence is being
transmitted by Facsimile to the Patent and Trademark
Office in accordance with 37 C.F.R. §1.6d on December
20, 1999.


David Denker, Reg. No. 40,987

Please amend the above-identified patent application as follows:

IN THE SPECIFICATION:

Page 1, lines 8 and 9, Please change "Serial No. TBD (TI-25859) and Serial No. TBD (TI-26146)"
to --Serial No. 09/115,855 and Serial No. 09/115,856 --.

Page 14, between lines 4 and 5, Please add a new paragraph.

Several metal silicates that address these preferences are zirconium silicate, cerium silicate,
zinc silicate, thorium silicate, bismuth silicate, hafnium silicate, lanthanum silicate, tantalum
silicate, and combinations thereof. The examples below will focus on zirconium silicate and
hafnium silicate.

IN THE CLAIMS:

Please cancel Claims 31 - 35.

Please amend Claim 25.

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